



## 100V 15mohm N-channel SGT MOSFET

### AKG100N15K

#### AKG100N15K Description

This N channel SGT MOSFET has been designed to very low on-state resistance ( $R_{DS(on)}$ ) and yet maintain superior switching performance, special for high efficiency power management applications.

#### AKG100N15K Features

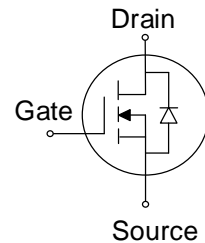
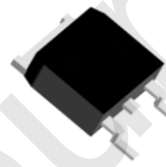
- N-channel, optimized for high-speed smooth switching
- Excellent Gate Charge  $\times R_{DS(on)}$  (FOM)
- Very low on-resistance
- RoHS compliant (Note 1)
- Halogen-free (Note 1)

#### AKG100N15K Applications

- DC-DC converter
- Power Management
- Motor Drivers
- Load switching

#### AKG100N15K Key Performance Parameters

Parameter	Value	Unit
$V_{DS}$	100	V
$R_{DS(on), max} @ V_{GS}=10V$	15	m $\Omega$
$I_D$	55	A



#### AKG100N15K Ordering Information

Ordering Code	Package Type	Marking Code	Form	Packing
AKG100N15K	TO-252	G100N15K	13 inches Reel	2500

#### Notes:

1. Contact ALKAIDSEMI sales for detail information



## AKG100N15K Maximum Ratings (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Value	Units
V <sub>DS</sub>	Drain-Source Voltage	100	V
I <sub>D</sub>	Drain Current - Continuous (T <sub>C</sub> = 25°C)	55	A
	Drain Current -Continuous (T <sub>C</sub> = 100°C)	35	A
I <sub>DM</sub>	Drain Current - Pulsed (Note 1,2)	220	A
V <sub>GS</sub>	Gate-Source Voltage	± 20	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 3)	8	mJ
P <sub>D</sub>	Power Dissipation (T <sub>C</sub> = 25°C)	83	W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	-55 to +150	°C

## AKG100N15K Thermal Characteristics

Symbol	Parameter	Value	Units
R <sub>θJC</sub>	Thermal Resistance, Junction-to-Case, Steady-State	1.5	°C/W
R <sub>θJA</sub>	Thermal Resistance, Junction-to-Ambient, Steady State (Note 4)	62.5	°C/W

### Notes:

1. The max drain current rating is package limited
2. Repetitive Rating: Pulse width limited by maximum junction temperature
3. L = 0.5 mH, V<sub>DD</sub> = 20 V, I<sub>AS</sub> = 5.5 A, R<sub>G</sub> = 25 Ω, Starting T<sub>J</sub> = 25 °C
4. Mount on minimum PCB layout



### AKG100N15K Electrical Characteristics ( $T_J = 25^\circ\text{C}$ unless otherwise noted)

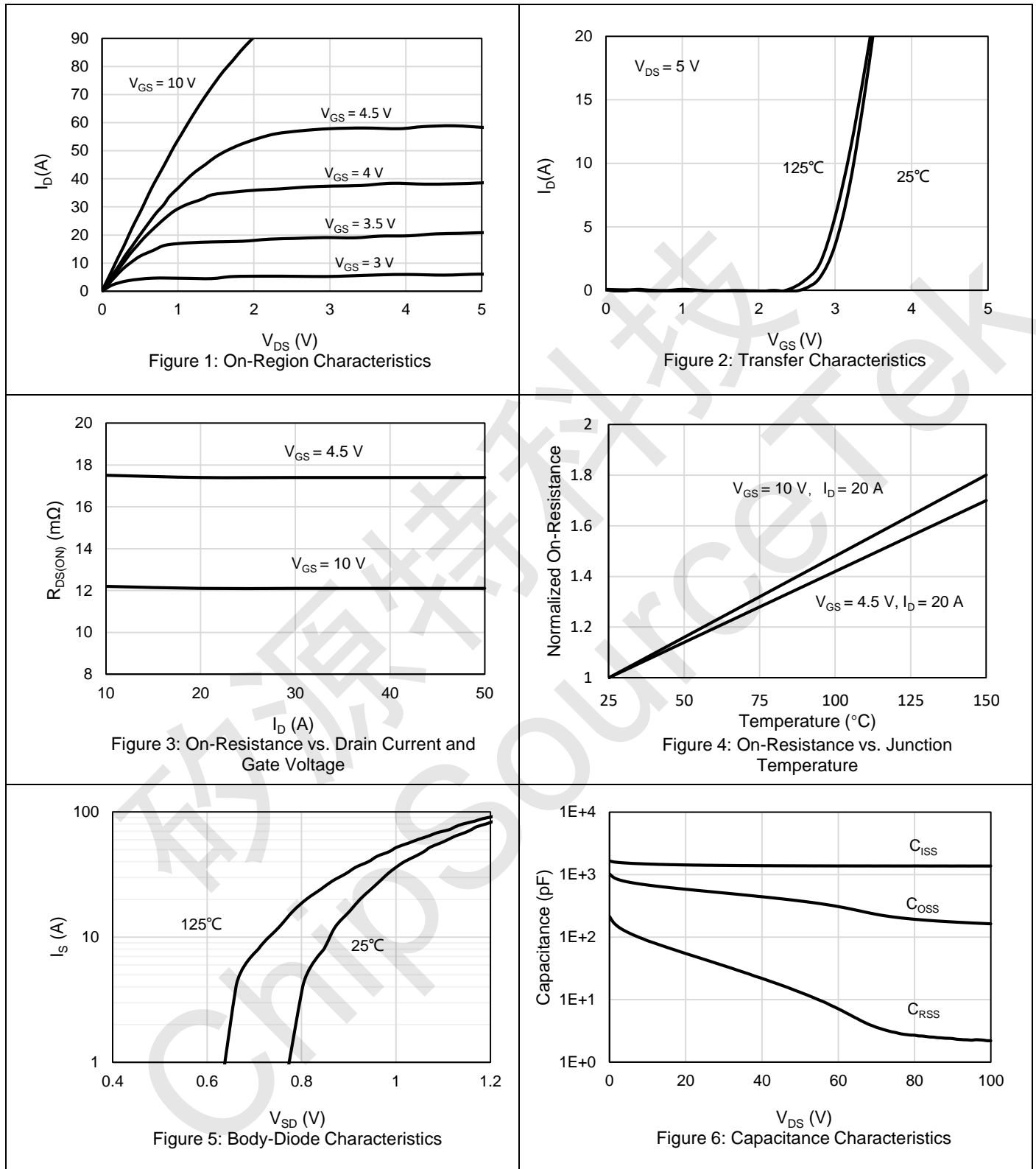
Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
<b>Static Characteristics</b>						
$BV_{DSS}$	Drain-Source Breakdown Voltage	$V_{GS} = 0\text{ V}, I_D = 250\ \mu\text{A}$	100			V
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{DS} = 80\text{ V}, V_{GS} = 0\text{ V}, T_J = 25^\circ\text{C}$			1	$\mu\text{A}$
$I_{GSS}$	Gate Leakage Current	$V_{GS} = \pm 20\text{ V}, V_{DS} = 0\text{ V}$			$\pm 100$	nA
$V_{GS(TH)}$	Gate Threshold voltage	$V_{DS} = V_{GS}, I_D = 250\ \mu\text{A}$	1.4	2	2.5	V
$R_{DS(on)}$	Drain-Source on-state resistance	$V_{GS} = 10\text{ V}, I_D = 20\text{ A}$		12.5	15	m $\Omega$
		$V_{GS} = 4.5\text{ V}, I_D = 20\text{ A}$		15.6	22.5	
<b>Dynamic Characteristics</b>						
$C_{ISS}$	Input capacitance	$V_{DS} = 50\text{ V}, V_{GS} = 0\text{ V}, F = 1\text{ MHz}$		1441		pF
$C_{OSS}$	Output capacitance			391		pF
$C_{RSS}$	Reverse transfer capacitance			15		pF
<b>Switching Characteristics</b>						
$T_{D(ON)}$	Turn On Delay Time	$V_{DS} = 50\text{ V}, I_D = 20\text{ A}, V_{GS} = 10\text{ V}, R_{GEN} = 10\ \Omega$		7		ns
$T_R$	Rise Time			26		ns
$T_{D(OFF)}$	Turn Off Delay Time			30		ns
$T_F$	Fall Time			12		ns
$Q_G$	Total Gate Charge	$V_{DS} = 50\text{ V}, I_D = 20\text{ A}, V_{GS} = 10\text{ V}$		22		nC
$Q_{GS}$	Gate-Source Charge			5		nC
$Q_{GD}$	Gate-Drain Charge			4		nC
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
$I_S$	Maximum Continuous Body-Diode Forward Current				55	A
$I_{SM}$	Maximum Pulsed Body-Diode Forward Current (NOTE 1)				220	A
$V_{SD}$	Diode Forward Voltage	$V_{GS} = 0\text{ V}, I_S = 20\text{ A}$		0.89		V
$T_{RR}$	Reverse recovery time	$I_F = 50\text{ A}, di/dt = 100\text{ A}/\mu\text{S}$		38		ns
$Q_{RR}$	Reverse recovery charge				39	

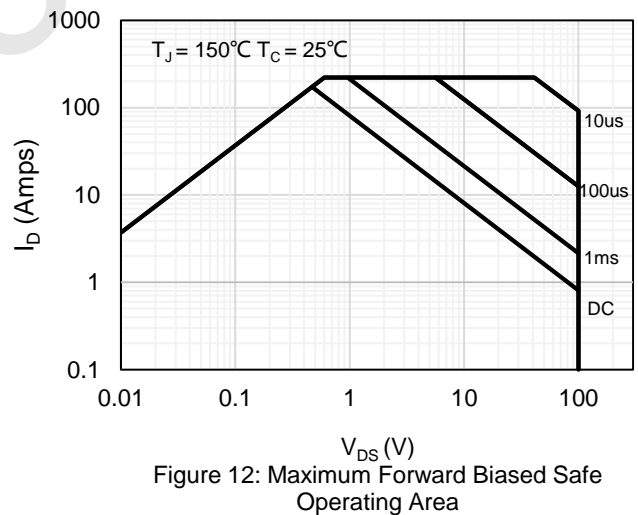
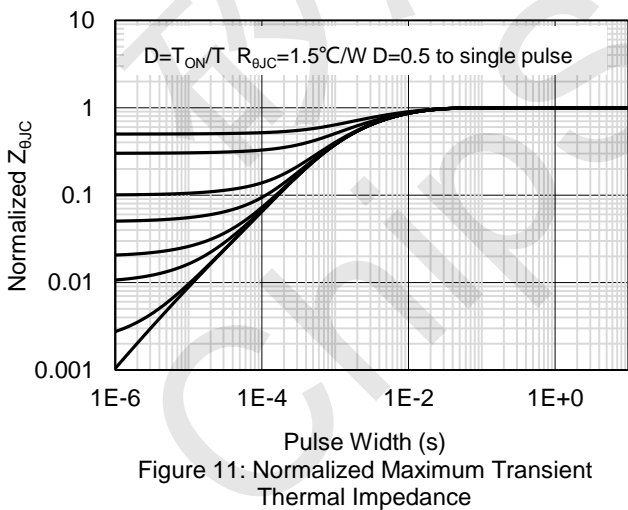
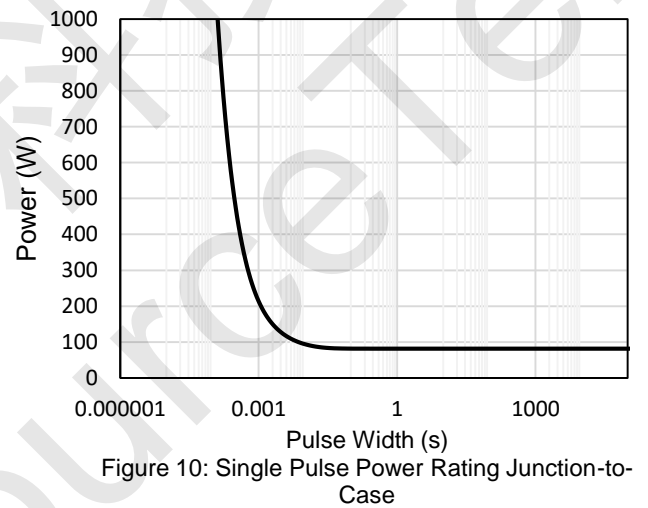
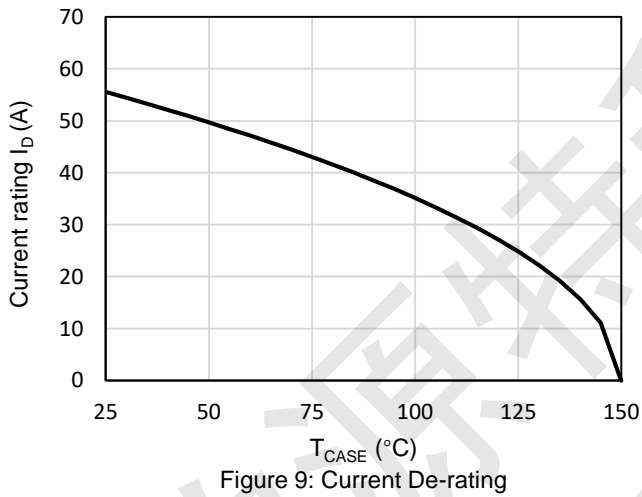
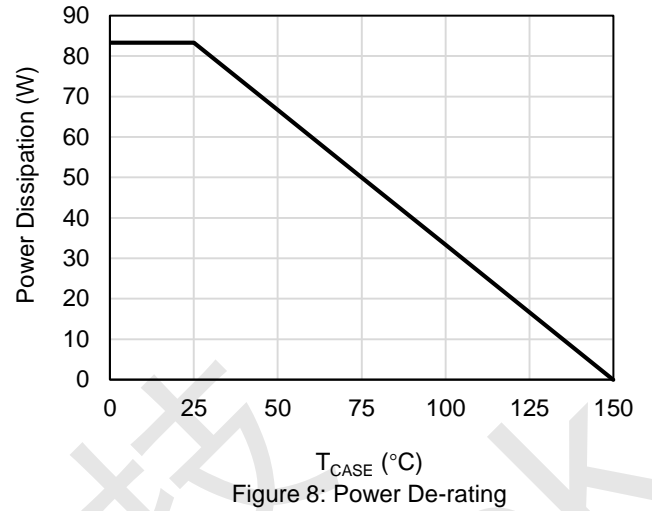
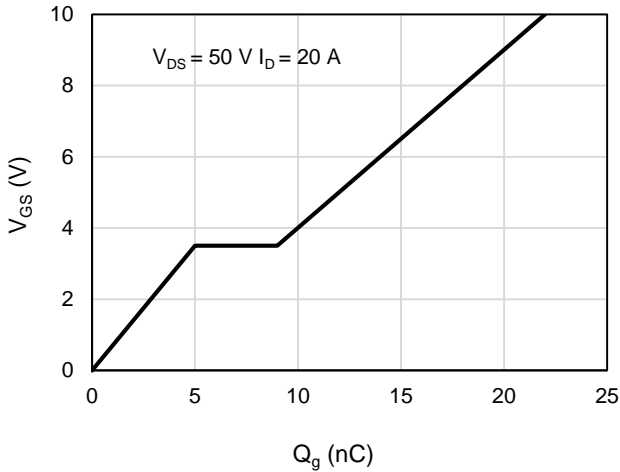
#### Notes:

1. Pulse Test: Pulse width  $\leq 300\ \mu\text{s}$ , Duty cycle  $\leq 2\%$
2. Essentially independent of operating temperature



## AKG100N15K Electrical Characteristics Diagrams

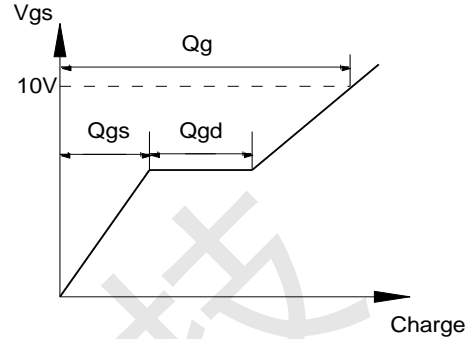
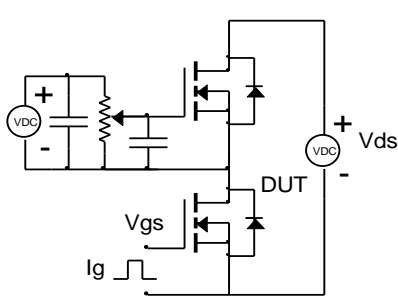




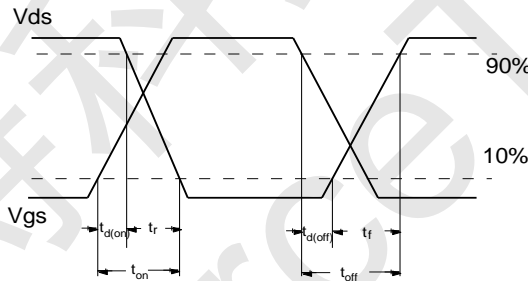
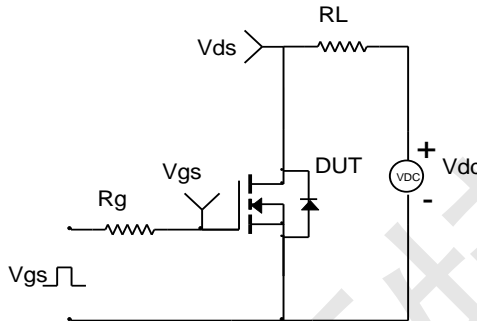


## AKG100N15K Test Circuit and Waveform

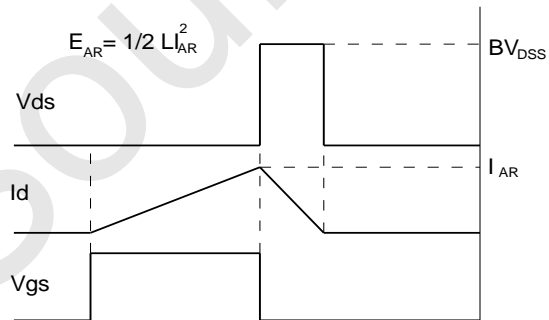
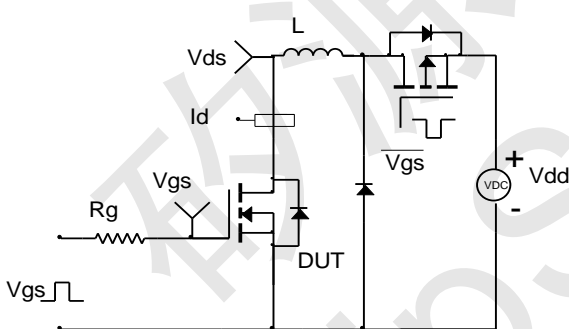
Gate Charge Test Circuit & Waveform



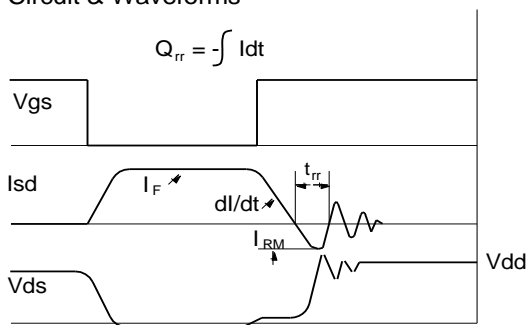
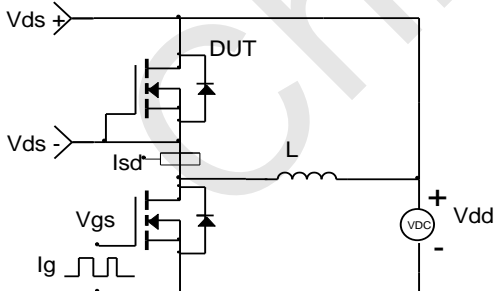
Resistive Switching Test Circuit & Waveforms



Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

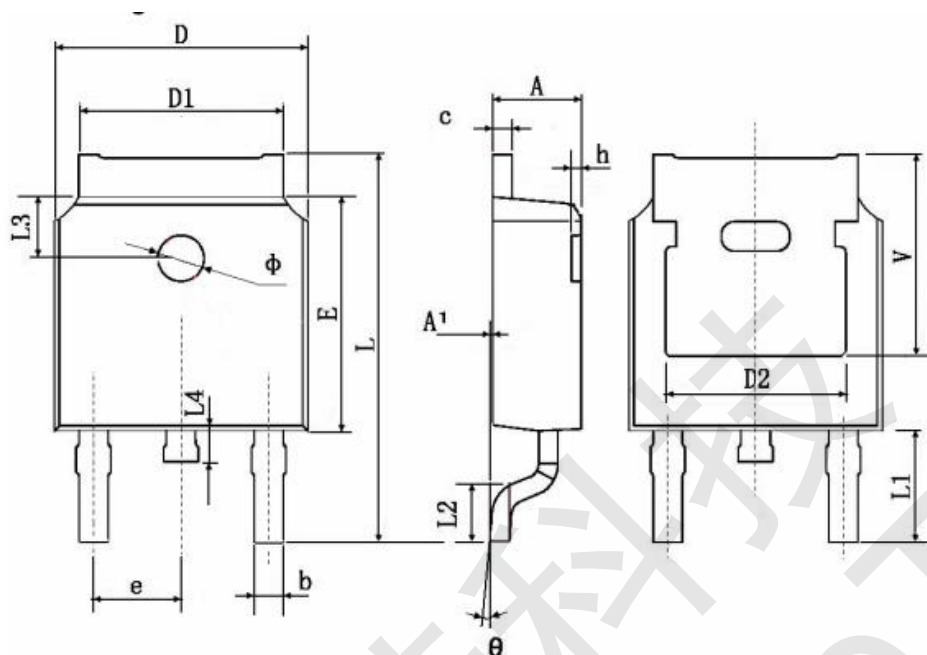


Diode Recovery Test Circuit & Waveforms





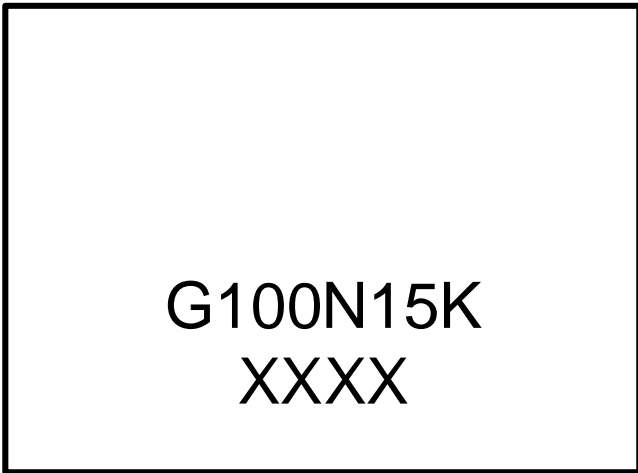
## AKG100N15K Package Outlines



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	2.250	2.350	0.089	0.093
A1	0.050	0.150	0.002	0.006
b	0.660	0.860	0.026	0.034
c	0.458	0.558	0.018	0.022
D	6.550	6.650	0.259	0.263
D1	5.234	5.434	0.207	0.215
D2	4.826 TYP.		0.191 TYP.	
E	6.050	6.150	0.239	0.243
e	2.236	2.336	0.088	0.092
L	9.820	10.220	0.388	0.404
L1	3.000 TYP.		0.119 TYP.	
L2	1.400	1.600	0.055	0.063
L3	1.800 TYP.		0.071 TYP.	
L4	0.700	0.900	0.028	0.036
phi	1.150	1.250	0.045	0.049
theta	0°	3°	0°	3°
h	0.000	0.300	0.000	0.012
V	5.399 TYP		0.213 TYP	



## AKG100N15K Marking Information



G100N15K  
XXXX

Note:

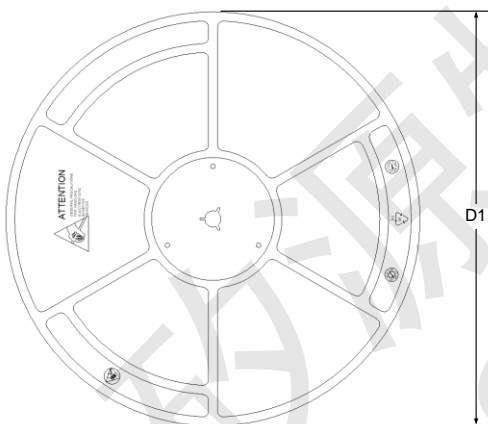
YYWW=Date code

G100N15K=Product Name Code

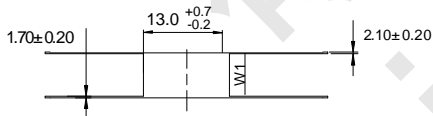
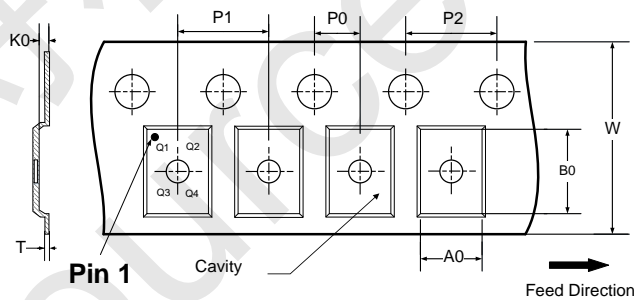
Contact ALKAIDSEMI sales for detail information

## Reel and Tube Information

REEL DIMENSIONS



TAPE DIMENSIONS



- A0: Dimension designed to accommodate the component width
- B0: Dimension designed to accommodate the component length
- K0: Dimension designed to accommodate the component thickness
- W: Overall width of the carrier tape
- P0: Pitch between successive cavity centers and sprocket hole
- P1: Pitch between successive cavity centers
- P2: Pitch between sprocket hole
- T: Tape material thickness
- D1: Reel Diameter
- W1: Reel Width

DIMENSIONS										(Unit: mm)
Reel	D1	W1								Material
	330	20.5								Hips
Tape	P0	P1	P2	W	A0	B0	K0	T	Pin 1 Quadrant	Material
	4	8	2	16	6.9	10.5	2.9	0.27	Q1	PC

All dimensions are nominal





## Revision History

Revision	Release Date	Remark
Rev. 1.0	2021-12-09	Initial Release

## Disclaimer

The information given in this document describes the independent performance of the product, but similar performance is not guaranteed under other working conditions, and cannot be guaranteed when installed with other products or equipment. To achieve the required performance of the product in actual scenarios, the customer should conduct a complete application test to assess the functionality of the product.

Alkaidsemi assumes no responsibility for equipment failures result from using products at values that exceed the ratings, operating conditions, or other parameters listed in the product specifications.

The product described in this specification is not applicable for aerospace or other applications which requires high reliability. Customers using or selling these products for use in medical, life-saving, or life-sustaining applications do so at their own risk and agree to fully indemnify.

Due to product or technical improvements, the information described or contained herein may be changed without prior notice.